MJE3439G

NPN Silicon High-Voltage Power Transistor

This device is designed for use in line-operated equipment requiring high $f_{\rm T}$.

Features

- High DC Current Gain
- High Current-Gain Bandwidth Product
- Low Output Capacitance
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	350	Vdc
Collector-Base Voltage	V _{CB}	450	Vdc
Emitter-Base Voltage	V _{EB}	5.0	Vdc
Collector Current – Continuous	I _C	0.3	Adc
Base Current	I _B	150	mAdc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	15 0.12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

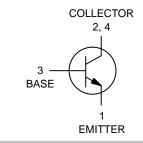
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$\theta_{\sf JC}$	8.33	°C/W



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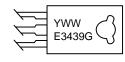
http://onsemi.com

0.3 AMPERE POWER TRANSISTOR NPN SILICON 350 VOLTS, 15 WATTS





MARKING DIAGRAM



Y = Year WW = Work Week E3439 = Device Code G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MJE3439G	TO-225 (Pb-Free)	500 Units/Box

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Symbol	Min	Max	Unit
V _{CEO(sus)}	350	_	Vdc
I _{CEO}	-	20	μAdc
I _{CEX}	-	500	μAdc
Ісво	-	20	μAdc
I _{EBO}	-	20	μAdc
h _{FE}	30 15	_ 200	_
V _{CE(sat)}	-	0.5	Vdc
V _{BE(sat)}	-	1.3	Vdc
V _{BE(on)}	-	0.8	Vdc
f _T	15	-	MHz
C _{ob}	-	10	pF
h _{fe}	25	-	-
	VCEO(sus) VCEO(sus)	VCEO(sus) 350	VCEO(sus) 350 - ICEO - 20 ICEX - 500 ICBO - 20 IEBO - 20 VCE(sat) - 0.5 VBE(sat) - 1.3 VBE(on) - 0.8 fT 15 - Cob - 10 hfe 10

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

MJE3439G

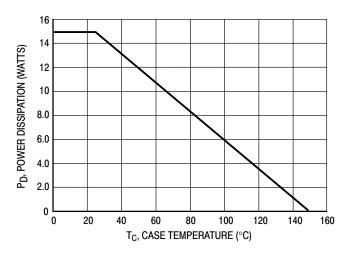


Figure 1. Power-Temperature Derating Curve

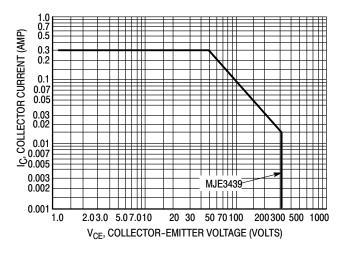
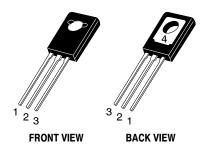


Figure 2. Active-Region Safe Operating Area

The Safe Operating Area Curves indicate $I_C - V_{CE}$ limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J , power–temperature derating must be observed for both steady state and pulse power conditions.

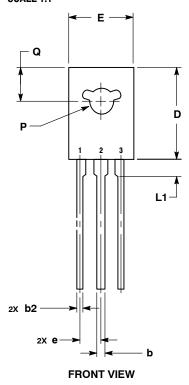
MECHANICAL CASE OUTLINE

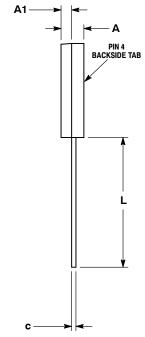


TO-225 CASE 77-09 **ISSUE AD**

DATE 25 MAR 2015

SCALE 1:1



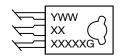


SIDE VIEW

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. NUMBER AND SHAPE OF LUGS OPTIONAL.

	MILLIMETERS				
DIM	MIN MAX				
Α	2.40	3.00			
A1	1.00	1.50			
b	0.60	0.90			
b2	0.51	0.88			
C	0.39	0.63			
D	10.60	11.10			
E	7.40	7.80			
е	2.04	2.54			
L	14.50	16.63			
L1	1.27	2.54			
P	2.90	3.30			
Q	3.80	4.20			

GENERIC MARKING DIAGRAM*



= Year

WW = Work Week XXXXX = Device Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

,		2., 4.	CATHODE ANODE GATE	2., 4.	BASE COLLECTOR EMITTER	,		,	MT 1 MT 2 GATE
2., 4.	CATHODE GATE		MT 1 GATE	2., 4.	SOURCE GATE	STYLE 9: PIN 1. 2., 4.	GATE DRAIN	2., 4.	SOURCE DRAIN
´3.	ANODE	3.	MT 2		DRAIN	3.	SOURCE	´3.	GATE

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